Octal Buffer/Line Driver with 3-State Outputs

The SN74LS240 and SN74LS244 are Octal Buffers and Line Drivers designed to be employed as memory address drivers, clock drivers and bus-oriented transmitters/receivers which provide improved PC board density.

- Hysteresis at Inputs to Improve Noise Margins
- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Input Clamp Diodes Limit High-Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Мах	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-3.0	mA
				-15	mA
I _{OL}	Output Current – Low			24	mA



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> LOW POWER SCHOTTKY



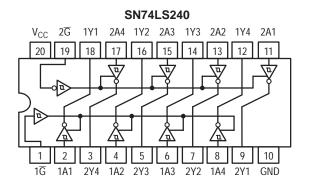
PLASTIC N SUFFIX CASE 738

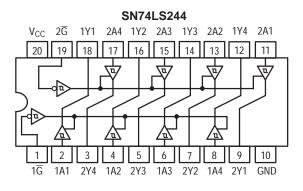


ORDERING INFORMATION

Device	Package	Shipping		
SN74LS240N	16 Pin DIP	1440 Units/Box		
SN74LS240DW	16 Pin	2500/Tape & Reel		
SN74LS244N	16 Pin DIP	1440 Units/Box		
SN74LS244DW	16 Pin	2500/Tape & Reel		

LOGIC AND CONNECTION DIAGRAMS DIP (TOP VIEW)





TRUTH TABLES

SN74LS240

INPU	OUTPUT		
1 <u>G</u> , 2 <u>G</u>	D	001901	
L	L	Н	
L H	H X	L (Z)	

H = HIGH Voltage LevelL = LOW Voltage LevelX = ImmaterialZ = HIGH Impedance SN74LS244

INP	OUTPUT	
1 <u>G</u> , 2 <u>G</u>	001901	
L	L	L
L	Н	Н
Н	Х	(Z)

http://onsemi.com 2

			Limits					
Symbol	Parameter		Min	Тур	Max	Unit	Test	Conditions
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Input LOW Voltage for All Inputs	
$V_{T+}-V_{T-}$	Hysteresis		0.2	0.4		V	V _{CC} = MIN	
V _{IK}	Input Clamp Diode Volta	age		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$	
M			2.4	3.4		V	$V_{CC} = MIN$, $I_{OH} = -3.0 \text{ mA}$	
V _{OH}	Output HIGH Voltage		2.0			V	V _{CC} = MIN, I _{OH} = MAX	
V _{OL}	Output LOW Voltage			0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$
				0.35	0.5	V	I _{OL} = 24 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
I _{OZH}	Output Off Current HIGH				20	μΑ	V _{CC} = MAX, V _{OL}	_{JT} = 2.7 V
I _{OZL}	Output Off Current LOW				-20	μΑ	V _{CC} = MAX, V _{OL}	_{JT} = 0.4 V
					20	μΑ	$V_{CC} = MAX, V_{IN}$	= 2.7 V
IIH	Input HIGH Current				0.1	mA	$V_{CC} = MAX, V_{IN}$	= 7.0 V
I _{IL}	Input LOW Current				-0.2	mA	$V_{CC} = MAX, V_{IN}$	= 0.4 V
I _{OS}	Output Short Circuit Current (Note 1)		-40		-225	mA	V _{CC} = MAX	
	Power Supply Current Total, Output HIGH				27			
	Total, Output LOW	LS240			44	1		
ICC	LS244 Total at HIGH Z LS240	LS244			46	mA V _{CC} = MAX		
		LS240			50	1		
	LS244				54	1		

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

		Limits				
Symbol	Parameter	Min	Тур	Мах	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay, Data to Output LS240		9.0 12	14 18	ns	
t _{PLH} t _{PHL}	Propagation Delay, Data to Output LS244		12 12	18 18	ns	$C_L = 45 \text{ pF},$ $R_L = 667 \Omega$
t _{PZH}	Output Enable Time to HIGH Level		15	23	ns	
t _{PZL}	Output Enable Time to LOW Level		20	30	ns	
t _{PLZ}	Output Disable Time from LOW Level		15	25	ns	C _L = 5.0 pF,
t _{PHZ}	Output Disable Time from HIGH Level		10	18	ns	R _L = 667 Ω

AC WAVEFORMS

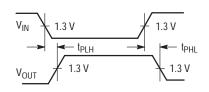


Figure 1.

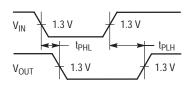


Figure 2.

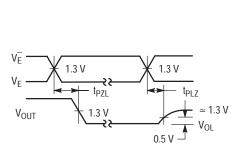
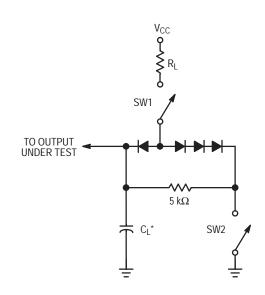


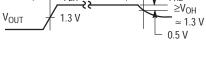
Figure 3.



SWITCH POSITIONS

SYMBOL	SW1	SW2		
t _{PZH}	Open	Closed		
t _{PZL}	Closed	Open		
t _{PLZ}	Closed	Closed		
t _{PHZ}	Closed	Closed		

Figure 5.



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1.3 V

t_{PHZ}

1.3 V

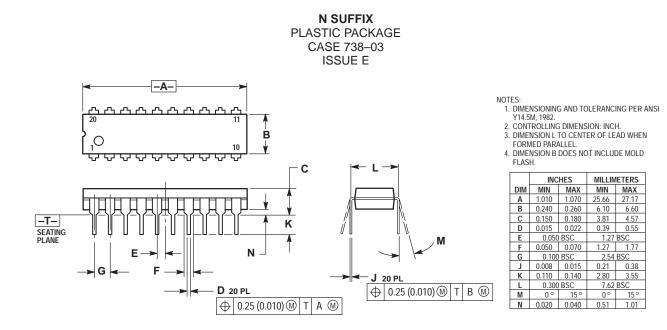
– t_{PZH}

Figure 4.

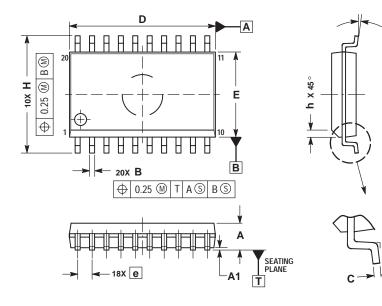
VE

 V_{E}

PACKAGE DIMENSIONS



D SUFFIX PLASTIC SOIC PACKAGE CASE 751D-05 ISSUE F



NOTES:

θ

NOTES:
DIMENSIONS ARE IN MILLIMETERS.
INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS						
DIM	MIN MAX						
Α	2.35	2.65					
A1	0.10	0.25					
В	0.35	0.49					
С	0.23	0.32					
D	12.65	12.95					
Ε	7.40	7.60					
е	1.27 BSC						
Н	10.05	10.55					
h	0.25	0.75					
L	0.50	0.90					
θ	0 °	7 °					

Notes

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